NSN 5962-01-226-4354

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inche	and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dis	sipation Rating:
794.0 milliwatts	
Operating Tempurat	ure Range:
55.0/+125.0 degrees	celsius
Storage Tempuratur	e Range:
65.0/+150.0 degrees	celsius
End Application:	
An/bps14to15e	
Features Provided:	
lermetically sealed a	nd burn in and programmable and bipolar and schottky
nclosure Material:	
Ceramic	
nclosure Configura	ion:
Dual-in-line	
Output Logic Form:	
ransistor-transistor I	ogic
nput Circuit Pattern	:
0 input	
Case Outline Source	And Designator:
D-2 mil-m-38510	
Terminal Surface Tr	eatment:
Solder	
/oltage Rating And	Type Per Characteristic:
0.5 volts power sour	ce and 7.0 volts power source
Fime Rating Per Cha	acteristic:
85.00 nanoseconds	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	2:
Prom	
Memory Capacity:	
Unknown	
Test Data Documen	:
	ndard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	
16 printed circuit	-
Shelf Life:	
N/a	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

